# Power MOSFET 170 mAmps, 100 Volts

## N-Channel SOT-23

#### **Features**

- AEC-Q101 Qualified and PPAP Capable BVSS123LT1G
- These Devices are Pb-Free and are RoHS Compliant

#### **MAXIMUM RATINGS**

| Rating   | Symbol                              | Value        | Unit       |
|--|-------------------------------------|--------------|------------|
| Drain-Source Voltage   | V <sub>DSS</sub>                    | 100          | Vdc        |
| Gate–Source Voltage<br>– Continuous<br>– Non–repetitive ( $t_p \le 50 \mu s$ ) | V <sub>GS</sub><br>V <sub>GSM</sub> | ±20<br>±40   | Vdc<br>Vpk |
| Drain Current - Continuous (Note 1) - Pulsed (Note 2)                          | I <sub>D</sub>                      | 0.17<br>0.68 | Adc        |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL CHARACTERISTICS

| Characteristic   | Symbol                            | Max         | Unit        |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board<br>(Note 3) T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 225<br>1.8  | mW<br>mW/°C |
| Thermal Resistance,<br>Junction-to-Ambient   | $R_{\theta JA}$                   | 556         | °C/W        |
| Junction and Storage Temperature   | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

- The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.
- 3. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

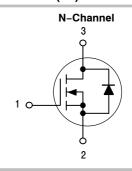


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170 mAMPS 100 VOLTS

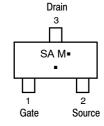
 $R_{DS(on)} = 6 \Omega$ 



# MARKING DIAGRAM & PIN ASSIGNMENT



SOT-23 CASE 318 STYLE 21



SA = Device Code M = Date Code

= Pb-Free Package

(\*Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

| Charac  | Symbol  | Min                 | Тур    | Max      | Unit  |      |
|---|---|---------------------|--------|----------|-------|------|
| OFF CHARACTERISTICS   |   |                     |        |          |       |      |
| Drain-Source Breakdown Voltage<br>(V <sub>GS</sub> = 0, I <sub>D</sub> = 250 μAdc)  | V <sub>(BR)DSS</sub>                                  | 100                 | -      | _        | Vdc   |      |
| Zero Gate Voltage Drain Current $(V_{GS}=0,V_{DS}=100\text{Vdc}) \qquad T_J=25^\circ\text{C} \\ \qquad T_J=125^\circ\text{C}$ | I <sub>DSS</sub>                                      | -<br>-              | -<br>- | 15<br>60 | μAdc  |      |
| Gate-Body Leakage Current (V <sub>GS</sub> = 20 Vdc, V <sub>DS</sub> = 0)   |   | I <sub>GSS</sub>    | -      | -        | 50    | nAdc |
| ON CHARACTERISTICS (Note 4)   |   |                     |        |          |       |      |
| Gate Threshold Voltage<br>(V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1.0 mAdc)                                     |   | V <sub>GS(th)</sub> | 0.8    | -        | 2.8   | Vdc  |
| Static Drain–Source On–Resistance (V <sub>GS</sub> = 10 Vdc, I <sub>D</sub> = 100 mAdc)                                       | r <sub>DS(on)</sub>                                   | -                   | 5.0    | 6.0      | Ω     |      |
| Forward Transconductance<br>(V <sub>DS</sub> = 25 Vdc, I <sub>D</sub> = 100 mAdc)   | 9 <sub>fs</sub>                                       | 80                  | -      | -        | mmhos |      |
| DYNAMIC CHARACTERISTICS   |   |                     |        |          |       |      |
| Input Capacitance<br>(V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)   |   | C <sub>iss</sub>    | -      | 20       | -     | pF   |
| Output Capacitance<br>(V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)  |   | C <sub>oss</sub>    | -      | 9.0      | -     | pF   |
| Reverse Transfer Capacitance<br>(V <sub>DS</sub> = 25 Vdc, V <sub>GS</sub> = 0, f = 1.0 MHz)                                  | C <sub>rss</sub>                                      | -                   | 4.0    | -        | pF    |      |
| SWITCHING CHARACTERISTICS(4)  |   |                     |        |          | •     | •    |
| Turn-On Delay Time  | (V <sub>CC</sub> = 30 Vdc, I <sub>C</sub> = 0.28 Adc, | t <sub>d(on)</sub>  | _      | 20       | _     | ns   |
| Turn-Off Delay Time   | $V_{GS}$ = 10 Vdc, $R_{GS}$ = 50 $\Omega$ )           | t <sub>d(off)</sub> | _      | 40       | -     | ns   |
| REVERSE DIODE   |   |                     |        |          |       |      |
| Diode Forward On–Voltage ( $I_D = 0.34$ Adc, $V_{GS} = 0$ Vdc)  |   | V <sub>SD</sub>     | _      | _        | 1.3   | V    |

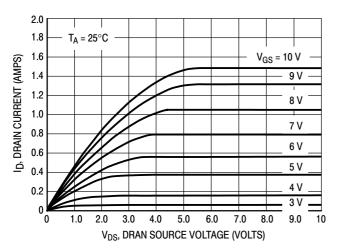
<sup>4.</sup> Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

## ORDERING INFORMATION

| Device      | Package             | Shipping <sup>†</sup> |
|-------------|---------------------|-----------------------|
| BSS123LT1G  | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |
| BSS123LT3G  | SOT-23<br>(Pb-Free) | 10000 / Tape & Reel   |
| BVSS123LT1G | SOT-23<br>(Pb-Free) | 3000 / Tape & Reel    |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### TYPICAL ELECTRICAL CHARACTERISTICS



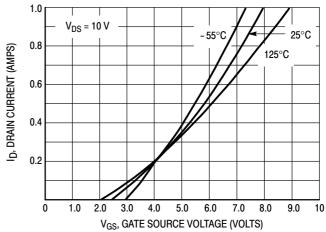
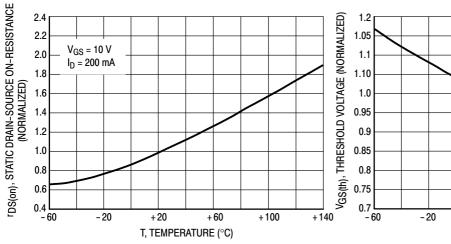


Figure 1. Ohmic Region

Figure 2. Transfer Characteristics



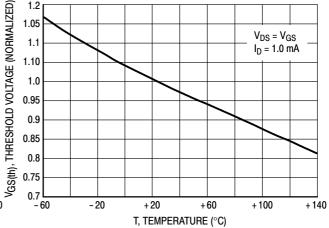


Figure 3. Temperature versus Static Drain-Source On-Resistance

Figure 4. Temperature versus Gate Threshold Voltage

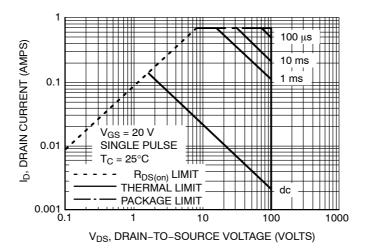


Figure 5. Maximum Rated Forward Biased Safe Operating Area

### TYPICAL ELECTRICAL CHARACTERISTICS

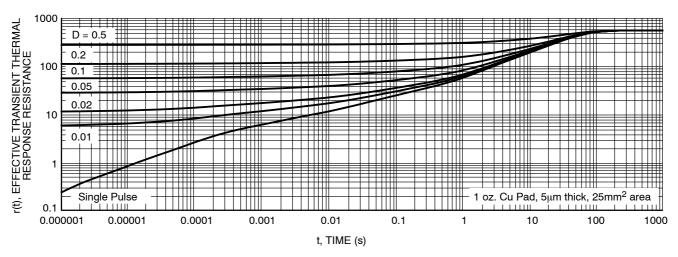
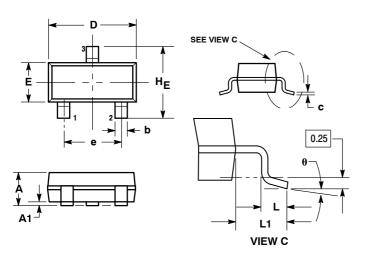


Figure 6. Thermal Response

#### PACKAGE DIMENSIONS

#### SOT-23 (TO-236) CASE 318-08 **ISSUE AP**



#### NOTES

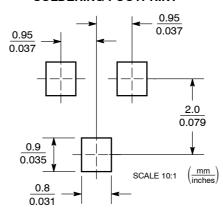
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
- PROTRUSIONS, OR GATE BURRS

|     | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
| DIM | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| Α   | 0.89        | 1.00 | 1.11 | 0.035  | 0.040 | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.37        | 0.44 | 0.50 | 0.015  | 0.018 | 0.020 |
| С   | 0.09        | 0.13 | 0.18 | 0.003  | 0.005 | 0.007 |
| D   | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| E   | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| е   | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.081 |
| L   | 0.10        | 0.20 | 0.30 | 0.004  | 0.008 | 0.012 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.029 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |
| θ   | 0°          |      | 10°  | 0°     |       | 10°   |

# STYLE 21: PIN 1. GATE

- SOURCE
- DRAIN

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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